/ Descriptions

TO-92(R) NPN Silicon NPN transistor in a TO-92(R) Plastic Package.

/ Features

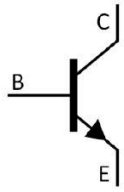
,

Low current, low voltage.

/ Applications

High-speed switching.

/ Equivalent Circuit



/ Pinning



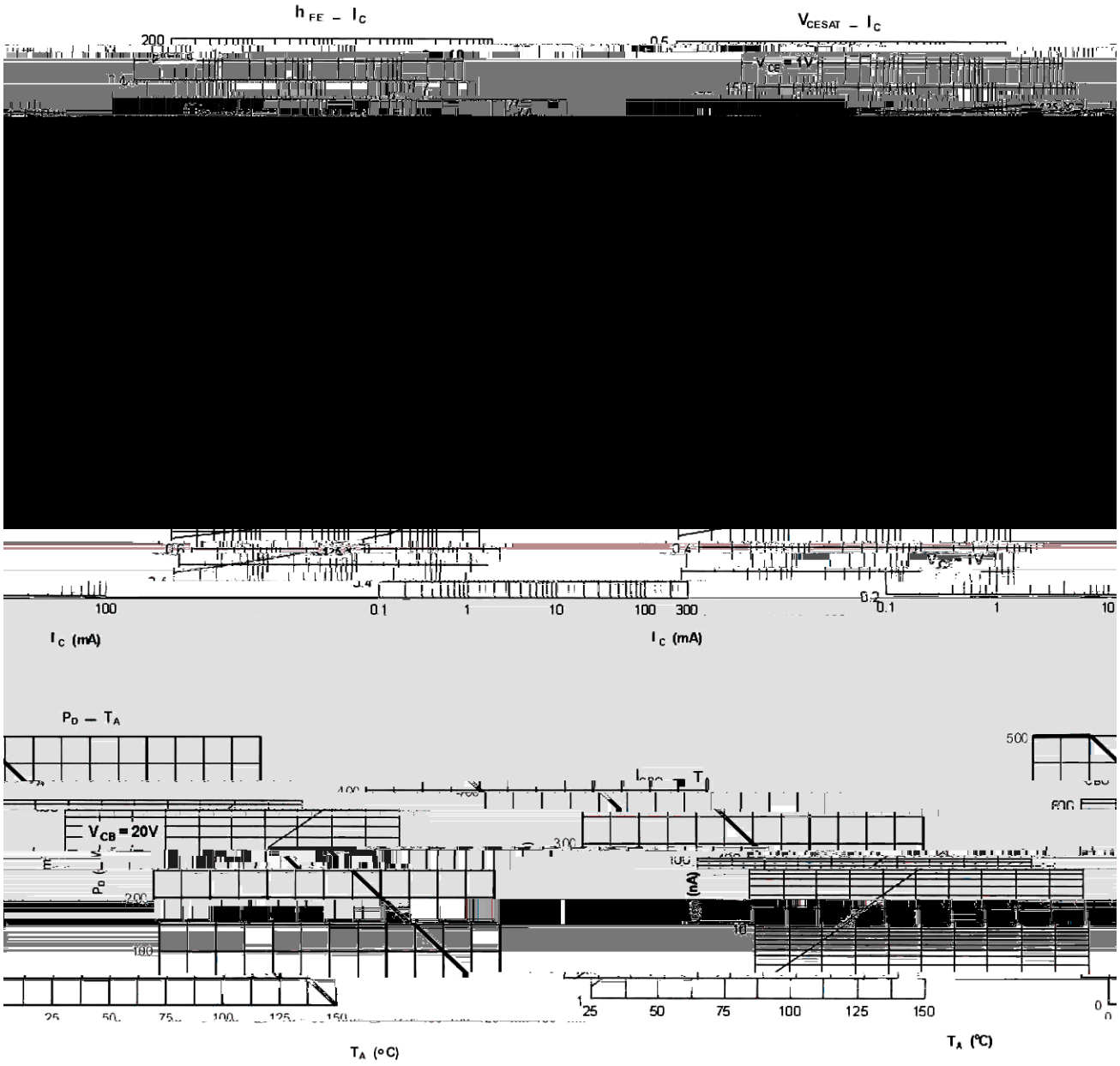
PIN1 Emitter PIN 2 Base PIN 3 Collector

/ h_{FE} Classifications & Marking

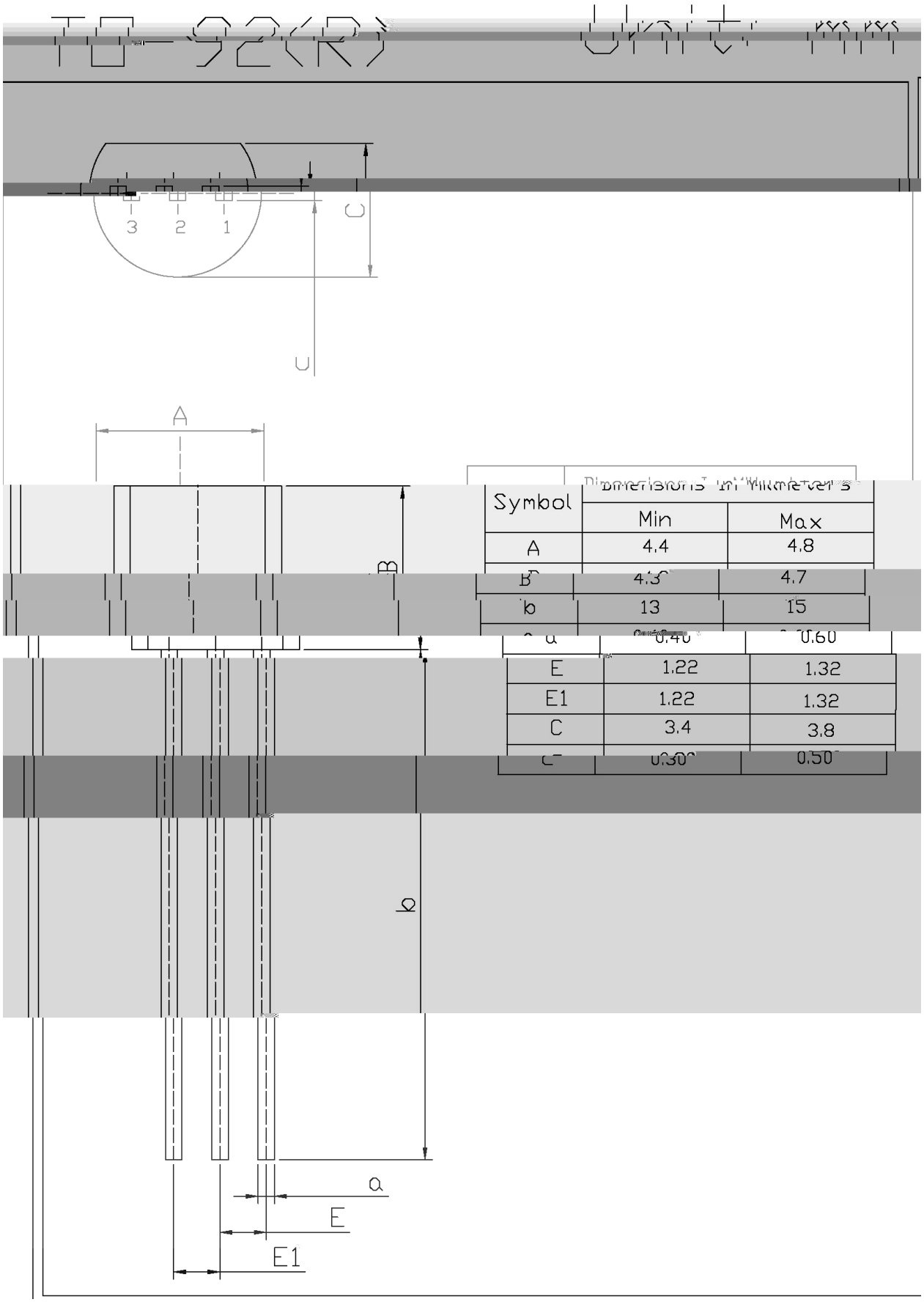
See Marking Instructions.

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	40	V
Collector to Emitter Voltage	V_{CEO}	15	V
Emitter to Base Voltage	V_{EBO}	4.5	V
Collector Current - Continuous	I_C	200	mA
Peak Collector Current	I_{CM}	300	mA

/ Electrical Characteristic Curve

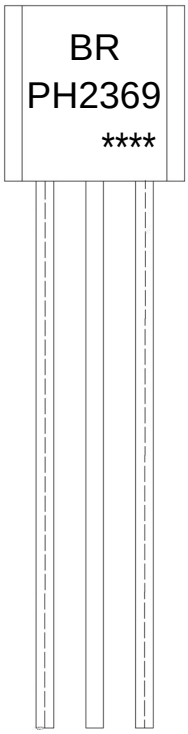


/ Package Dimensions



Symbol	Dimensions In Millimeters	
	Min	Max
A	4.4	4.8
B	4.3	4.7
b	13	15
a	0.40	0.60
E	1.22	1.32
E1	1.22	1.32
C	3.4	3.8
c	0.30	0.50

/ Marking Instructions



BR

PH2369

****

Note:

BR:	Company Code.
PH2369:	Product Type.
****:	Lot No. Code, code change with Lot No.

( ) / Temperature Profile for Dip Soldering(Pb-Free)



				Note:	
1	25	150	60 90sec;	1.Preheating:25~150	, Time:60~90sec.
2	255±5		5±0.5sec;	2.Peak Temp.:255±5	, Duration:5±0.5sec.
3		2 10	/sec.	3. Cooling Speed: 2~10	/sec.

/ Resistance to Soldering Heat Test Conditions

270±5	10±1 sec.	Temp.:270±5	Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-92	1,000	10	10,000	5	50,000	135×190	237×172×102	560×245×195
	1,000	10	10,000	10	100,000	135×190	237×172×102	560×245×375

/ AMMO

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)	
	Units/tape 只/纸带	Tape/Inner Box 纸带/盒	Rows/Inner Box 纸带层/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Inner Box 盒	Outer Box 箱
TO-92	3,000	1	120	10	30,000	328×230×42	小箱 480×346×235， 大箱 547×407×268

/ Notices